WHITE LED STEP-UP CONVERTER





Description

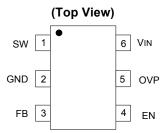
The AP5724 is a step-up DC/DC converter specifically designed to drive white LEDs with a constant current. The device can drive $2 \sim 6$ LEDs in series from a Li-lon cell. Series connection of the LEDs provides identical LED currents resulting in uniform brightness and eliminates the need for ballast resistors. For driving higher number of LEDs, AP5724 also supports a single feedback of parallel connected multiple strings of equal number of LEDs.

The AP5724 switches at 1.2MHz that allows the use of tiny external components. A low 0.1V feedback voltage minimizes power loss in the current setting resistor for better efficiency

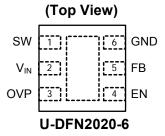
Features

- High Efficiency: 84% Typical
- Fast 1.2MHz Switching Frequency
- Current Limit and UVLO Protections
- Internal Thermal Shutdown
- Internal Over Voltage Protection
- Integrated Soft-Start Function
- SOT26, TSOT26 and U-DFN2020-6: Available in "Green" Molding Compound (No Br, Sb)
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)

Pin Assignments



SOT26 / TSOT23-6



Applications

- Cellular Phones
- PDAs, Hand held Computers
- Digital Cameras
- MP3 Players
- GPS Receivers

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

Typical Applications Circuit

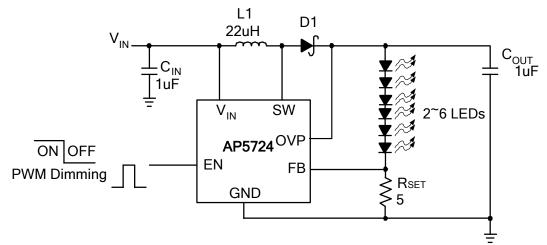


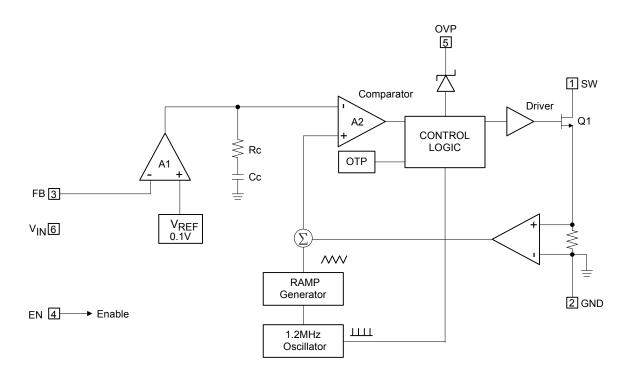
Figure 1 Typical Application Circuit



Pin Descriptions

Pin Name	Functions
SW	Switch Pin. Connect inductor/diode here. Minimize trace area at this pin to reduce EMI.
GND	GND pin.
FB	Feedback Pin. Reference voltage is 0.1V. Connect cathode of lowest LED and a sense resister here. Calculate resistor value according to the formula: R _{SET} = 0.1V / ILED
EN	Converter On/Off Control Input. A high input at EN turns the converter On, and a low input turns it off. If On/Off control is not needed, connect EN to the input source for automatic startup. The EN pin cannot be left floating.
OVP	Output Voltage detect pin for over voltage protection.
V _{IN}	Input Supply Pin. Must be locally bypassed with 1µF or 2.2µF to reduce input noise.

Functional Block Diagram



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
V _{IN}	VIN Pin Voltage	-0.3 to +7	V
VSW	SW Voltage	-0.3 to +34	V
V _{OVP}	OVP Pin Voltage	-0.3 to +35	V
V_{FB}	Feedback Pin Voltage	-0.3 to +7	V
EN	EN	-0.3 to +7	V
$T_{J(MAX)}$	Maximum Junction Temperature	150	°C
T _{LEAD}	Lead Temperature	300	°C
T _{ST}	Storage Temperature Range	-65 to +150	°C

Caution: Operation above the absolute maximum ratings can cause device failure. These values, therefore, must not be exceeded under any condition.

Operation at the absolute maximum rating for extended periods, may reduce device reliability.



Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V_{IN}	Input Voltage	2.7	5.5	V
TJ	Operating Junction Temperature	-40	125	°C
T _A	Operating Ambient Temperature	-40	85	°C

Electrical Characteristics (@ V_{IN} = 3.6V, T_A = +25°C, unless otherwise specified.)

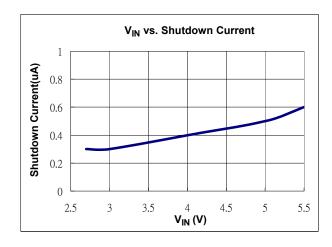
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
System Supp	ly Input	•		•	•	
V _{IN}	Operating Input Voltage		2.7	_	5.5	V
UVLO	Under Voltage Lockout		_	2.2	2.4	V
	Under Voltage Lockout Hysteretic		_	85	_	mV
IQ	Quiescent Current	FB = 0.2V, No Switching	_	500	_	μΑ
I _{SD}	Shutdown Current	V _{EN} < 0.4V	_	0.1	1	μΑ
Oscillator	·			•		
Fosc	Operation Frequency		1	1.2	1.4	MHz
Dmax	Maximum Duty Cycle		86	90	_	%
Reference Vo	Itage			•		
V _{FB}	Feedback Voltage		0.09	0.1	0.11	V
I _{FB}	FB Pin Bias Current		10	45	100	nA
MOSFET			-	•	•	
Rds(on)	On Resistance of MOSFET		_	0.95	1.2	Ω
I _{OCP}	Switching Current Limit	Normal Operation	_	750	_	mA
Control and P	rotection			•		
EN	Voltage High	ON	1.5	_	_	V
EN	Voltage Low	OFF	_	_	0.4	V
I _{EN}	EN Pin Pull Low Current		_	4	6	μΑ
OVP	OVP Threshold		26	30	34	V
		SOT26 (Note 3)	_	162	_	
θ_{JA}	Thermal Resistance Junction-to-Ambient	TSOT26 (Note 3)	_	152	_	°C/W
		U-DFN2020-6 (Note 3)	_	200	_	
		SOT26 (Note 3)	_	36	_	
θЈС	Thermal Resistance Junction-to-Case	TSOT26 (Note 3)		32	_	°C/W
		U-DFN2020-6 (Note 3)	_	30	_	

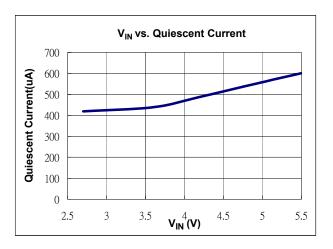
Note:

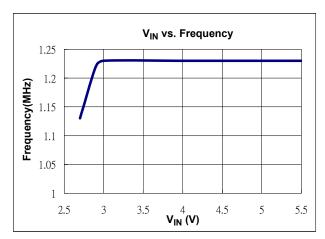
^{3.} Test condition for SOT26, TSOT26 and U-DFN2020-6: Device mounted on FR-4 substrate, single-layer PC board, 2oz copper, with minimum recommended pad layout

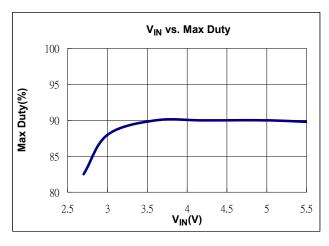


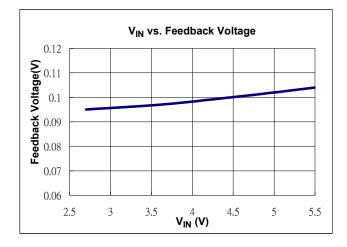
Typical Performance Characteristics (6 LEDS, V_{IN} = 3.6V, I_{OUT} = 25mA)

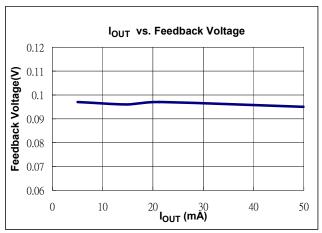






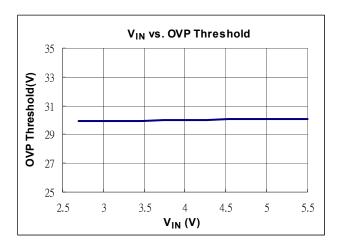


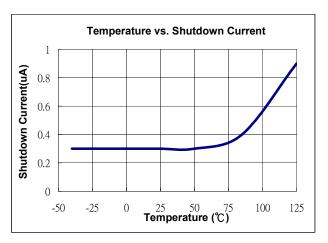


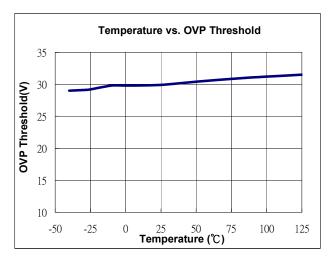


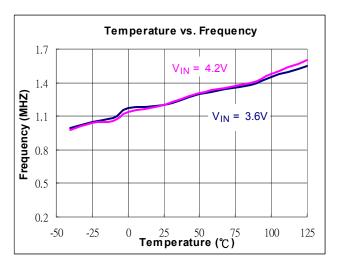


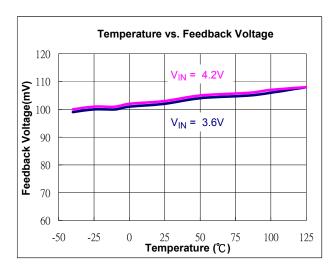
Typical Performance Characteristics (cont.) (6 LEDS, V_{IN} = 3.6V, I_{OUT} = 25mA)





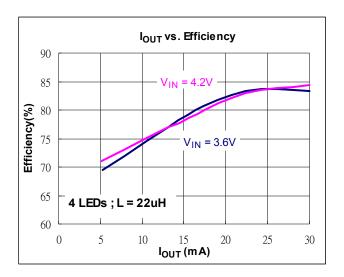


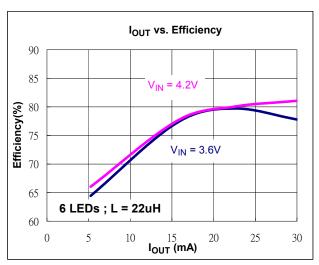


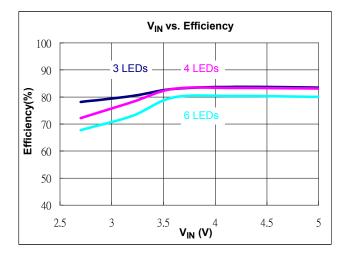




Typical Performance Characteristics (cont.) (6 LEDS, VIN = 3.6V, IOUT = 25mA)

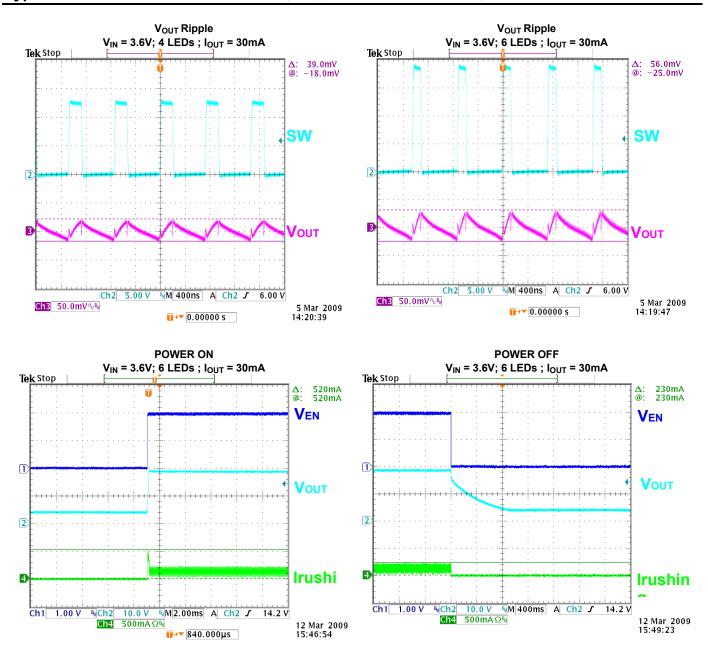








Typical Performance Characteristics (cont.) (6 LEDS, VIN = 3.6V, IOUT = 25mA)





Applications Information

Inductor Selection

A 10µH to 22µH inductor is recommended for most AP5724 applications. For high efficiency the inductor should have low core losses at 1.2MHz and low DCR (copper wire resistance). The inductor saturation current rating should also exceed the peak input current, especially for high load current applications (like 3S8P).

Capacitor Selection

The small size of the ceramic capacitors are ideal for AP5724 applications. X5R and X7R types are recommended because they retain their capacitance over wider voltage and temperature ranges than other types such as Y5V or Z5U. A $1\mu F$ input capacitor and a $1\mu F$ output capacitor are sufficient for most AP5724 applications. For high output current applications like 3S8P, larger output capacitor of $2.2\mu F$ to $4.7\mu F$ is recommended to minimize output ripple.

Diode Selection

Schottky diodes, with their low forward voltage drop and fast reverse recovery, are the ideal choices for AP5724 applications. The forward voltage drop of a Schottky diode represents the conduction losses in the diode, while the diode capacitance (C_T or C_D) represents the switching losses. For diode selection, both forward voltage drop and diode capacitance need to be considered. Schottky diodes with higher current ratings usually have lower forward voltage drop and larger diode capacitance, which can cause significant switching losses at the 1.2MHz switching frequency of the AP5724. Schottky diodes with higher current ratings usually have lower forward voltage drop and larger diode capacitance. Larger Schottky diode capacitance can cause significant switching losses at the 1.2MHz switching frequency of the AP5724. A Schottky diode rated at 100mA to 200mA is sufficient for most AP5724 applications.

LED Current Control

The LED current is controlled by the feedback resistor (R_{SET} in **Figure 1**). The feedback reference is 0.1V. The LED current is 0.1V/ R_{SET} . In order to have accurate LED current, precision resistors are preferred (1% is recommended). The formula and table for R_{SET} selection are shown below. $R_{SET} = 0.1V/I_{LED}$ (See **Table 1**)

Table 1. R_{SET} Resistor Value Selection

I _{LED} (mA)	R _{SET} (Ω)
5	20
10	10
15	6.6
20	5
30	3.3
40	2.5

Open-Circuit Protection

In the cases of output open circuit, when the LEDs are disconnected from the circuit or the LEDs fail, the feedback voltage will be zero. The AP5724 will then switch at a high duty cycle resulting in a high output voltage, which may cause the SW and OVP pin voltage to exceed the voltage rating of these pins. The OVP pin monitors the output voltage. If the output voltage reaches the over voltage protection threshold at the OVP pin (**Figure 2**), the over voltage protection is activated and SW pin stops switching.

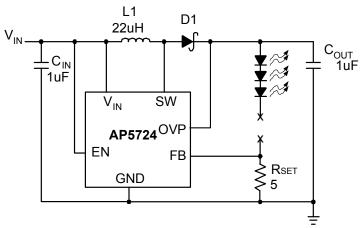


Figure 2 LED Driver with Open-Circuit Protection



Applications Information (cont.)

Dimming Control

There are four different types of dimming control circuits:

1. Using a PWM Signal to EN Pin

With the PWM signal applied to the EN pin, the AP5724 is turned on or off by the PWM signal. The LEDs operate at either zero or full current. The average LED current increases proportionally with the duty cycle of the PWM signal. A 0% duty cycle will turn off the AP5724 and corresponds to zero LED current. A 100% duty cycle corresponds to full current. The typical frequency range of the PWM signal is below 2 kHz.

2. Using a DC Voltage

For some applications, the preferred method of brightness control is a variable DC voltage to adjust the LED current. The dimming control using a DC voltage is shown in **Figure 3**. As the DC voltage increases, the voltage drop on R2 increases and the voltage drop on R_{SET} decreases. Thus, the LED current decreases. The selection of R2 and R3 will make the current from the variable DC source much smaller than the LED current and much larger than the FB pin bias current. For V_{DC} range from 0V to 2V, the selection of resistors in **Figure 3** gives dimming control of LED current from 0mA to 20mA.

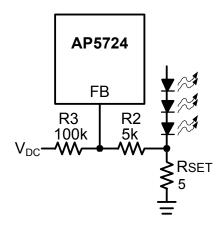


Figure 3 Dimming Control Using a DC Voltage

3. Using a Filtered PWM Signal

The filtered PWM signal can be considered as an adjustable DC voltage. It can be used to replace the variable DC voltage source in dimming control

4. Using a Logic Signal

For applications that need to adjust the LED current in discrete steps, a logic signal can be used as shown in **Figure 4**. R_{SET} sets the minimum LED current (when the NMOS is off). R_{SET} sets how much the LED current increases when the NMOS is turned on.

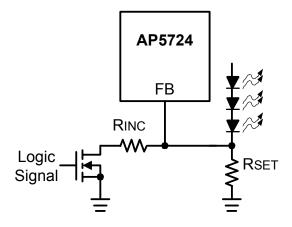


Figure 4 Dimming Control Using a Logic Signal



Applications Information (cont.)

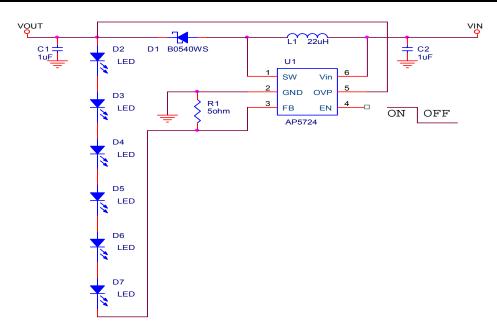


Table 2. Suggested Inductors

Vendor	Inductors (µH)	Current Rating (A)	Туре	Dimensions (mm)	Series
Wurth Electronics	22	0.51A	SMD	3.8X 3.8 X 1.6	744031220
GOTREND	22	0.56A	SMD	3.8 X 3.8 X 1.05	GLP3810PH220N
TAIYO YUDRN	22	0.51A	SMD	4.0 X 4.0 X 1.25	NR4012

Table 3. Suggested Capacitors for C_{IN} and C_{OUT}

Ī	Vendor	Capacitance	Туре	Series
	TAIYO YUDEN	1µF	SMD	TMK212 B7105MG-T

Table 4. Suggested Diodes

Table 4. Oaggestea Bload	abio ii daggootaa bidaco						
Vendor	Rating	Туре	Series				
ZETEX	40V/0.5A	SOD323	ZLLS400				
DIODES	40V/0.5A	SOD323	B0540WS				
DIODES	40V/0.25A	SOD523	SDM20U40				

Table 5. Suggested Resistor

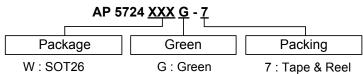
Vendor	Туре	Series
YAGEO	SMD	FR-SK

Table 6. Suggested W-LED

Vendor	Туре	Series
LITEON	SMD	LTW-C1911UC5



Ordering Information



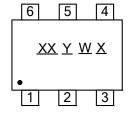
WU: TSOT26 FDC: U-DFN2020-6

Daut Neumbau	Dookens Code	Dookoaina	7" Tape	and Reel
Part Number Package Code		Packaging	Quantity	Part Number Suffix
AP5724WG-7	W	SOT26	3000/Tape & Reel	-7
AP5724WUG-7	WU	TSOT26	3000/Tape & Reel	-7
AP5724FDCG-7	FDC	U-DFN2020-6	3000/Tape & Reel	-7

Marking Information

SOT26 and TSOT26 (1)

(Top View)



XX: Identification Code

Y : Year 0~9

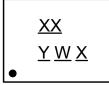
W: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents 52 and 53 week

X: A~Z: Green

Part Number	Package	Identification Code
AP5724WG-7	SOT26	FB
AP5724WUG-7	TSOT26	GB

(2) U-DFN2020-6

(Top View)



XX: Identification Code

Y: Year: 0~9

W: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents 52 and 53 week

X : A~Z : Green

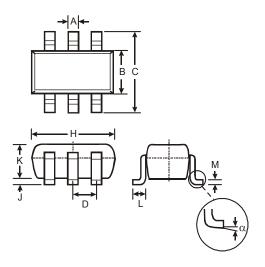
Part Number	Package	Identification Code
AP5724FDCG-7	U-DFN2020-6	GB



Package Outline Dimensions (All dimensions in mm.)

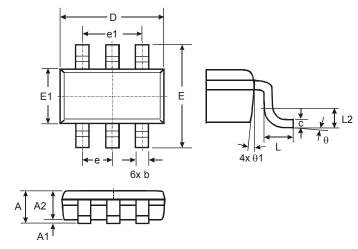
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(1) SOT26



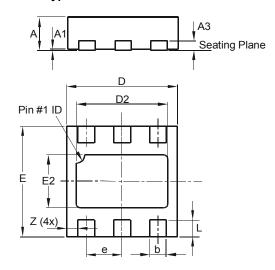
SOT26			
Dim	Min	Max	Тур
Α	0.35	0.50	0.38
В	1.50	1.70	1.60
С	2.70	3.00	2.80
D	_	_	0.95
Н	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	
All Dimensions in mm			

(2) TSOT26



TSOT26			
Dim	Min	Max	Тур
Α	_	1.00	_
A1	0.01	0.10	-
A2	0.84	0.90	-
D	-	-	2.90
Ε	-	_	2.80
E1	-	-	1.60
b	0.30	0.45	-
С	0.12	0.20	-
е	-	_	0.95
e1	_	_	1.90
L	0.30	0.50	
L2	-	_	0.25
θ	0°	8°	4°
θ1	4°	12°	-
All Dimensions in mm			

(3) U-DFN2020-6 Type C



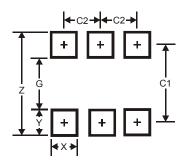
U-DFN2020-6			
Type C			
Dim	Min	Max	Тур
Α	0.57	0.63	0.60
A1	0.00	0.05	0.02
A3	_		0.15
b	0.25	0.35	0.30
D	1.95	2.075	2.00
D2	1.55	1.75	1.65
E	1.95	2.075	2.00
E2	0.86	1.06	0.96
е			0.65
L	0.25	0.35	0.30
Z			0.20
All Dimensions in mm			



Suggested Pad Layout

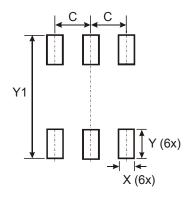
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) SOT26



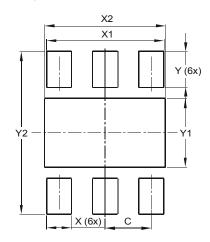
Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Υ	0.80
C1	2.40
C2	0.95

(2) TSOT26



Dimensions	Value (in mm)
С	0.950
Х	0.700
Y	1.000
Y1	3.199

(3) U-DFN2020-6 Type C

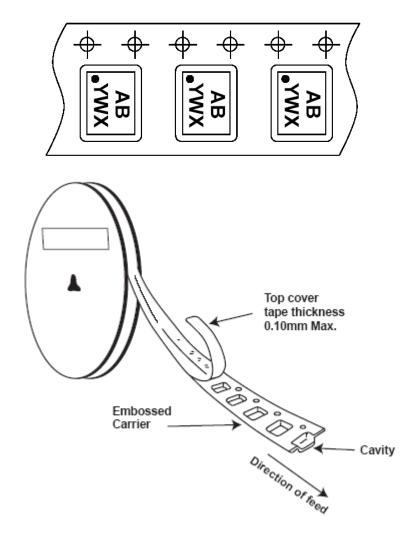


Dimensions	Value
	(in mm)
С	0.650
X	0.350
X1	1.650
X2	1.700
Y	0.525
Y1	1.010
Y2	2.400



Tape Orientation

For U-DFN2020-6



Note: 4. The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf.



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Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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